788-144

Pages Issue Date

## HN58V256A Series HN58V257A Series

32768-word × 8-bit Electrically Erasable and Programmable CMOS ROM

# **HITACHI**

ADE-203-357 A (Z) Rev. 1.0 Apr. 12, 1996

#### Description

The Hitachi HN58V256A and HN58V257A are a electrically erasable and programmable EEPROM's organized as 32768-word  $\times$  8-bit. Employing advanced MNOS memory technology and CMOS process and circuitry technology. They also have a 64-byte page programming function to make their write operations faster.

#### **Features**

- Single 2.7 to 5.5 V supply
- On-chip latches: address, data, CE, OE, WE
- Automatic byte write: 10 ms max
- Automatic page write (64 bytes): 10 ms max
- Fast access time: 120 ns max
- Low power dissipation: active: 20 mW/MHz, (typ) standby: 110 µW (max)
- Ready/Busy (only the HN58V267A series)
- · Data polling and Toggle bit
- Data protection circuit on power on/off
- Conforms to JEDEC byte-wide standard
- Reliable CMOS with MNOS cell technology
- 10<sup>5</sup> erase/write cycles (in page mode)
- 10 years data retention
- Software data protection
- Write protection by RES pin (only the HN58V267A series)
- Industrial versions (Temperatur range: -20 to 85°C and -40 to 85°C) are also available.

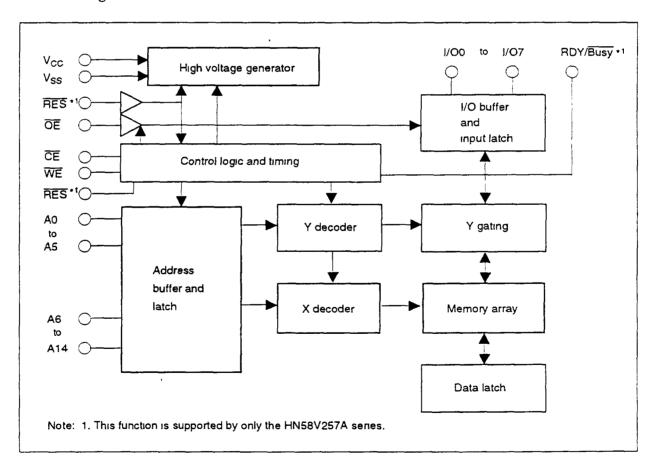


#### Pin Description

Pin name	Function
A0 to A14	Address input
I/O0 to I/O7	Data input/output
ŌĒ	Output enable
CE	Chip enable
WE	Write enable *
V <sub>cc</sub>	Power supply
V <sub>ss</sub>	Ground
RDY/Busy*1	Ready busy
RES*1	Reset
NC	No connection

Note: 1. This function is supported by only the HN58V257A series.

#### **Block Diagram**



HITACHI

#### **Recommended DC Operating Conditions**

Parameter		Symbol	Min	Тур	Max	Unit
Supply voltage		V <sub>cc</sub>	2.7	3.0	5.5	٧
Input voltage	out voltage V <sub>II</sub>		-0.31	_	0.6	V
		V <sub>IH</sub>	1.9~2	_	V <sub>cc</sub> + 0.3 <sup>-3</sup>	V
		V <sub>H</sub> *4	V <sub>cc</sub> - 0.5	-	V <sub>cc</sub> + 1.0	٧
Operating temperature	*	Topr	0		70	°C

Notes 1.  $V_{IL}$  min: -1.0 V for pulse width  $\leq$  50 ns.

- 2.  $V_{H}$  min for  $V_{CC} = 3.6$  to 5.5 V is 2.4 V.
- 3.  $V_{\text{IH}}$  max:  $V_{\text{cc}}$  + 1.0 V for pulse width  $\leq$  50 ns.
- 4. This function is supported by only the HN58V257A series.

### DC Characteristics (Ta = 0 to +70°C, $V_{CC} = 2.7$ to 5.5 V)

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions
input leakage current	l <sub>u</sub>			2"	μΑ	V <sub>cc</sub> = 5.5 V, Vin = 5 5 V
Output leakage current	I <sub>LO</sub>		_	2	μΑ	V <sub>cc</sub> = 5.5 V, Vout = 5.5/0.4 V
V <sub>cc</sub> current (standby)	I <sub>cc1</sub>		_	20	μΑ	CE = V <sub>cc</sub>
	l <sub>cc2</sub>		_	1	mA	CE = V <sub>IH</sub>
V <sub>cc</sub> current (active)	l <sub>ccs</sub>	-	_	8	mA	lout = 0 mA, Duty = 100%, Cycle = 1 $\mu$ s at $V_{cc}$ = 3.6 V
				12	mA	lout = 0 mA, Duty = 100%, Cycle = 1 $\mu$ s at $V_{cc}$ = 5 5 V
			_	12	mA	lout = 0 mA, Duty = 100%, Cycle = 120 ns at V <sub>cc</sub> = 3.6 V
				30	mA	lout = 0 mA, Duty = 100%, Cycle = 120 ns at V <sub>cc</sub> = 5.5 V
Output low voltage	V <sub>oL</sub>			0.4	V	I <sub>oL</sub> = 2.1 mA
Output high voltage	V <sub>OH</sub>	$V_{cc} \times 0.8$	_	_	V	I <sub>OH</sub> = -400 μA

Note: 1.  $I_{U}$  on  $\overline{RES} = 100 \mu A \text{ max}$  (only the HN58V257A series)

#### Capacitance (Ta = 25°C, f = 1 MHz)

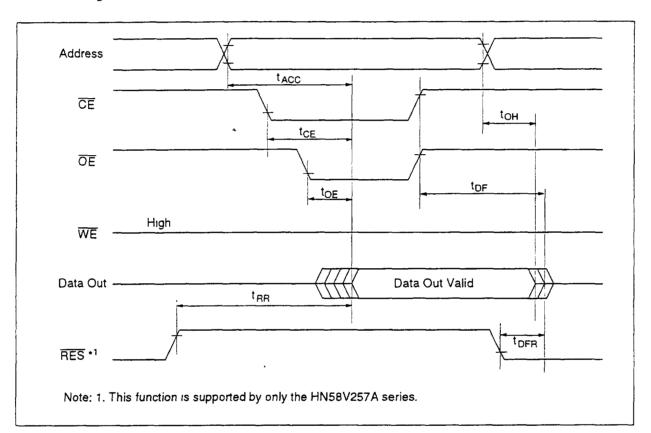
Parameter	Symbol	Min	Тур	Max	Unit	Test conditions
Input capacitance*1	Cin	_	_	6	рF	Vin = 0 V
Output capacitance*1	Cout	_	_	12	pF	Vout = 0 V

Note: 1. This parameter is periodically sampled and not 100% tested.

023 . 1 4.96

### HN58V256A Series, HN58V257A Series

#### Read Timing Waveform

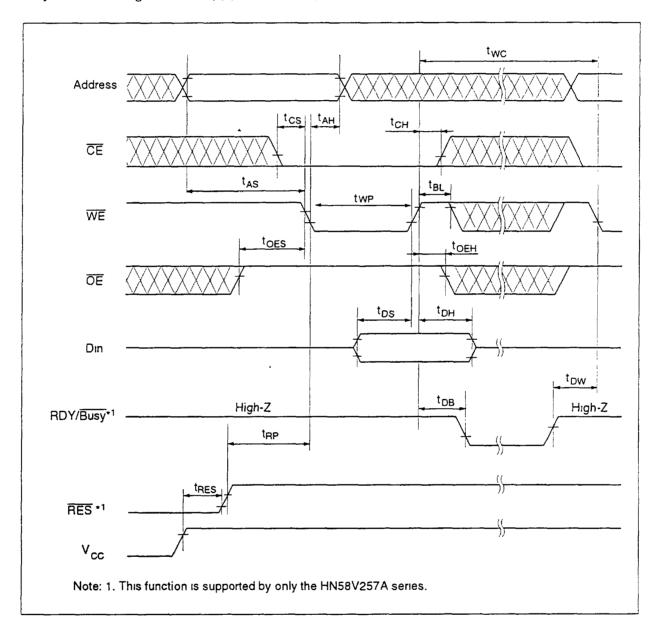


Pages lesue Data

023 .1 4.96

### HN58V256A Series, HN58V257A Series

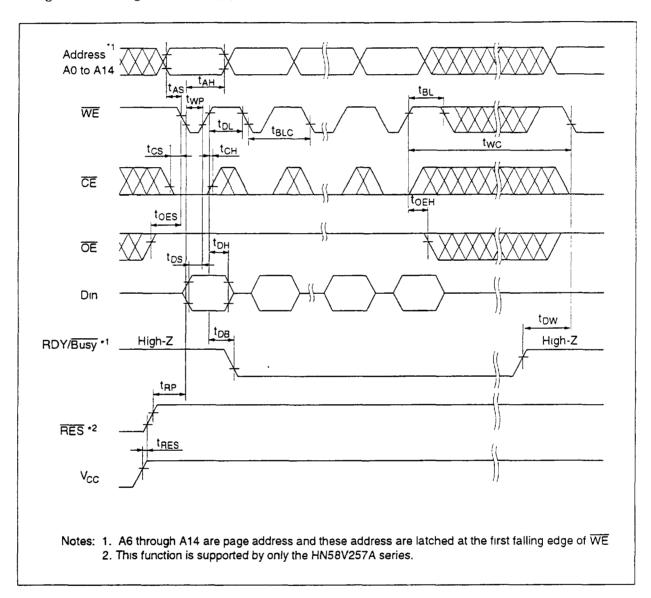
Byte Write Timing Waveform (1) (WE Controlled)



023 . 1 4.96

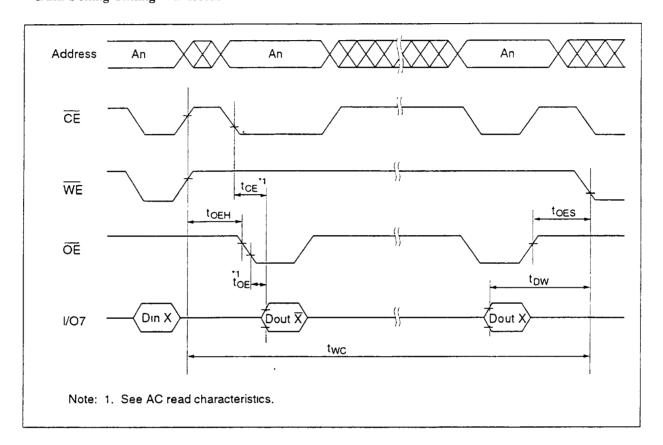
### HN58V256A Series, HN58V257A Series

#### Page Write Timing Waveform (1) (WE Controlled)





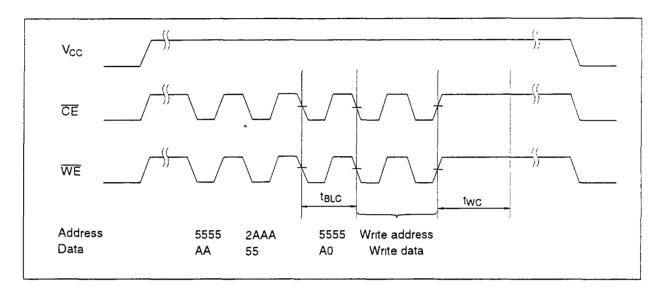
### Data Polling Timing Waveform



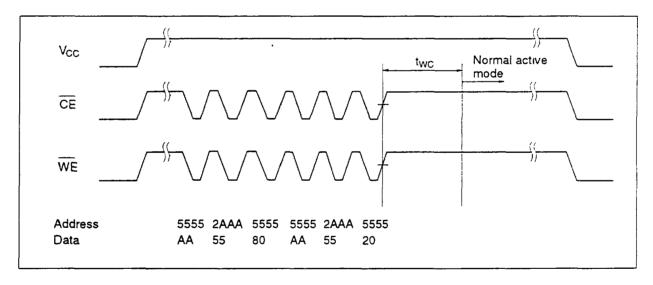
023 . 1 4.96

### HN58V256A Series, HN58V257A Series

### Software Data Protection Timing Waveform (1) (in protection mode)



#### Software Data Protection Timing Waveform (2) (in non-protection mode)



#### WE, CE Pin Operation

During a write cycle, addresses are latched by the falling edge of  $\overline{WE}$  or  $\overline{CE}$ , and data is latched by the rising edge of  $\overline{WE}$  or  $\overline{CE}$ .

#### Write/Erase Endurance and Data Retention Time

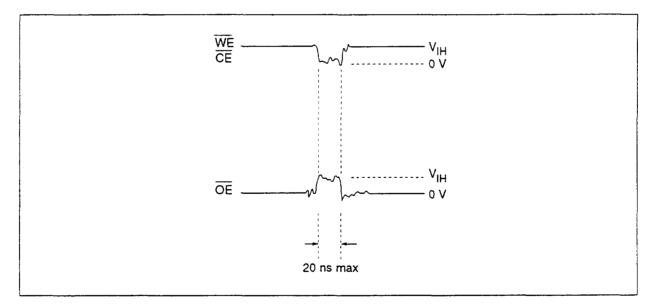
The endurance is  $10^5$  cycles in case of the page programming and  $10^4$  cycles in case of the byte programming (1% cumulative failure rate). The data retention time is more than 10 years when a device is page-programmed less than  $10^4$  cycles.

#### **Data Protection**

1. Data Protection against Noise on Control Pins ( $\overline{CE}$ ,  $\overline{OE}$ ,  $\overline{WE}$ ) during Operation During readout or standby, noise on the control pins may act as a trigger and turn the EEPROM to programming mode by mistake.

To prevent this phenomenon, this device has a noise cancelation function that cuts noise if its width is 20 ns or less in program mode.

Be careful not to allow noise of a width of more than 20 ns on the control pins.



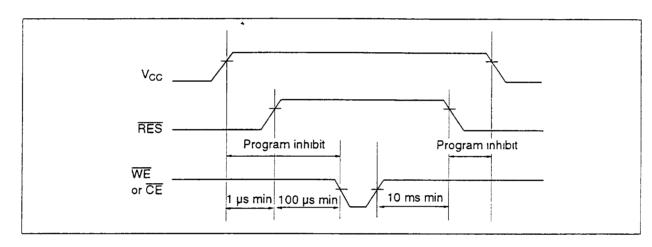
023 - 1 4,96

### HN58V256A Series, HN58V257A Series

#### (2) Protection by $\overline{RES}$ (only the HN58V257A series)

The unprogrammable state can be realized by that the CPU's reset signal inputs directly to the EEPROM's  $\overline{RES}$  pin  $\overline{RES}$  should be kept  $V_{SS}$  level during  $V_{CC}$  on/off

The EEPROM breaks off programming operation when  $\overline{RES}$  becomes low, programming operation doesn't finish correctly in case that  $\overline{RES}$  falls low during programming operation  $\overline{RES}$  should be kept high for 10 ms after the last data input.



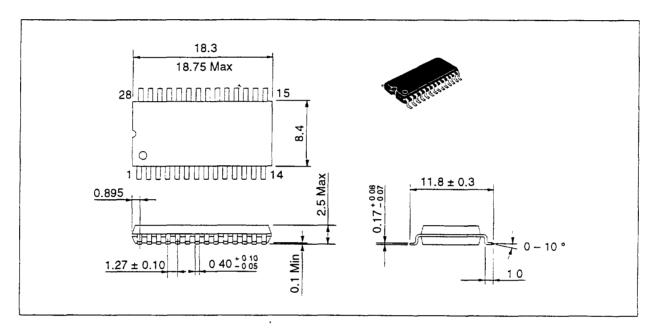
023 .1 4.96

### HN58V256A Series, HN58V257A Series

#### **Package Dimensions**

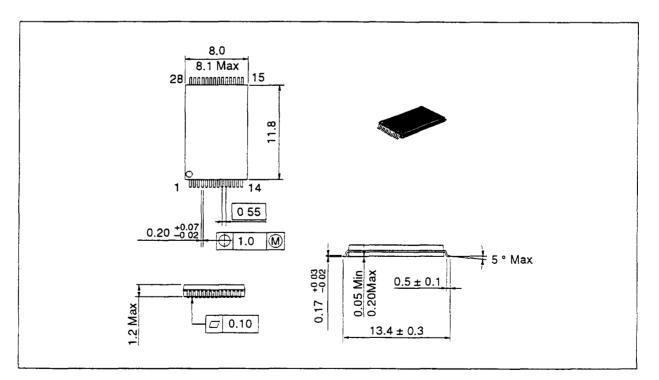
HN58V256AFP Series (FP-28D)

Unit mm



HN58V256AT Series (TFP-28DB)

Unit- mm



HITACHI

When using this document, keep the following in mind:

- 1. This document may, wholly or partially, be subject to change without notice
- 2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
- 3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
- 4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein
- 5 No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
- MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.

# **HITACHI**

Hitachi, Ltd.
Semiconductor & IC Div
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100, Japan Tel: Tokyo (03) 3270-2111
Fax (03) 3270-5109

For further information write to: Hitachi America, Ltd. Semiconductor & IC Div. 2000 Sierra Point Parkway Brisbane, CA. 94005-1835 USA Tel 415-589-8300 Fax 415-583-4207

Hitachi Europe GmbH Electronic Components Group Continental Europe Dornacher Straße 3 D-85622 Feldkirchen München Tel: 089-9 91 80-0 Fax. 089-9 29 30 00 Hitachi Europe Ltd.
Electronic Components Div
Northern Europe Headquarters
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA
United Kingdom
Tel 0628-585000
Fax 0628-778322

Hitachi Asia Pte Ltd 16 Collyer Quay #20-00 Hitachi Tower Singapore 0104 Tel: 535-2100 Fax 535-1533

Hitachi Asia (Hong Kong) Ltd Unit 706, North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon Hong Kong Tel 27359218 Fax 27306071